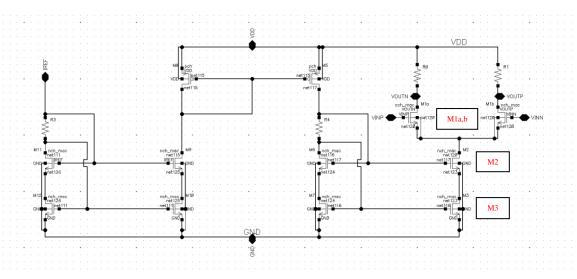
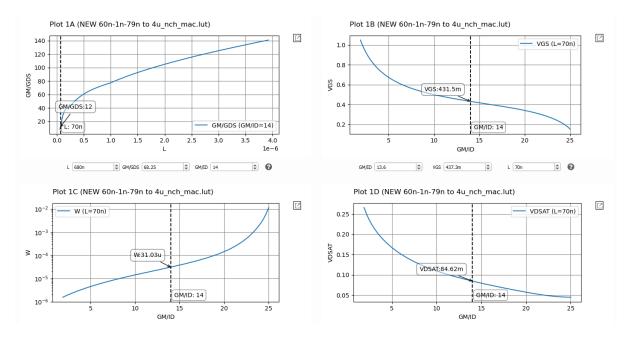
Use gm/ID methodology to design a diff input diff output operational transconductance amplifier (OTA) that achieves the following specs.

Spec.			
DC Gain	0 dB	Linear Range	300 mVpp
BW	≥ 15 GHz	CMRR	≥ 40 dB
Power Consumption	≤ 2.5 mW	Cap Load	100 fF
Reference Current	10 uA		



Design of the input pair

$$\begin{split} P_{cons} &= V_{DD} \ I_{ss} \leq 2.5 \ mW \to I_{ss} \leq 2 \ mA \\ GBW &= \frac{g_{m1}}{2\pi C_L} \geq 15 \ GHz \to g_{m1} \geq 9.43 \ mS \\ g_{m1} &= 14 \ mS \to \frac{g_{m1}}{I_D} = 14 \\ A_v &= g_{m1} R_{out} = 1 \to R_{out} = 71.5 \ \Omega \to R_D = 80 \ \Omega \to r_{o1} \geq 673 \ \Omega \to \frac{g_{m1}}{g_{ds}} \geq 9.5 \\ V_{out} &= V_{DD} - I_{D1} * R_D = 1.12 \ V \\ Assume \ V_{DS1} &= 500 \ mV \\ L_1 &= 70 \ nm, V_{GS1} = 431.5 \ mV, W_1 = 31.03 \ um \end{split}$$



Designing the Current Mirror circuit

$$I_{SS\;max}=2\;mA=a1*a2*I_{REF} \rightarrow a1*a2=200 \rightarrow Choose\;a1=20\;and\;a2=10$$

$$\text{CMRR} = 2g_m*R_{SS} = 100 \rightarrow R_{SS} \geq 4.4 \text{ k}\Omega \rightarrow R_{SS} = 4.5 \text{k}\Omega$$

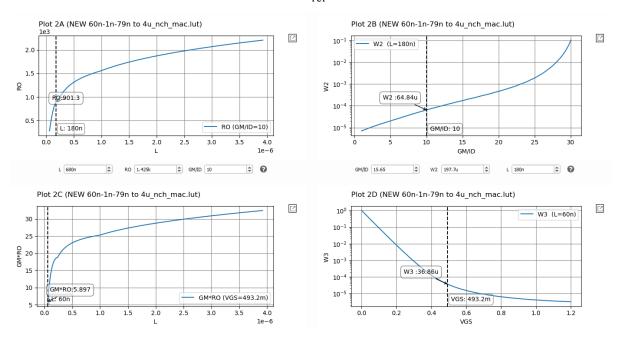
use
$$L_{CM}=3*L_{min}=180$$
 nm \rightarrow reduce $\frac{1}{f}$ noise and bias it in SI: $\left(\frac{g_m}{I_D}\right)_3=10$

$$W_3 = 64.84 \text{ um}, r_{o3} = 901.3 \Omega, V_{GS3} = 493.2 \text{ mV}$$

$$(g_m.r_o)_2 = 5 \rightarrow L_2 = 60 \text{ nm}$$

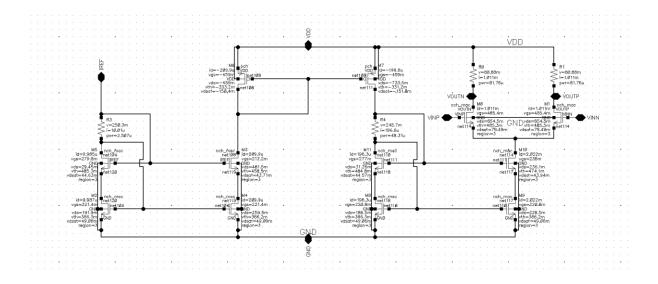
Assume
$$V_{GS2} = V_{GS3} = 493.2 \text{ mV} \rightarrow W_2 = 36.86 \text{ um}$$

For
$$R_{CM} = \frac{V_{DS3}}{I_{ref}} = 25000$$

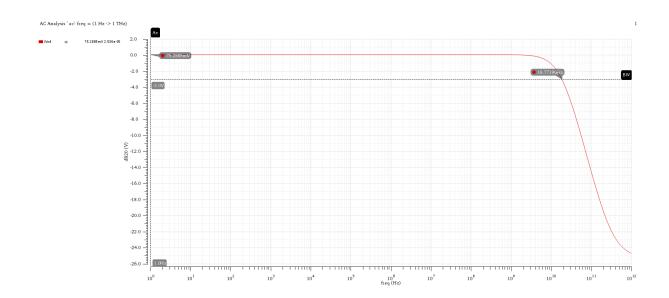


$\underline{\rm Simulations}$

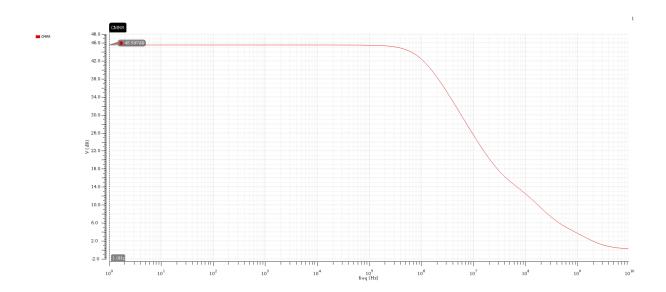
DC OP



Av Differential



CMRR



CMIR

